

CentralTM Semiconductor Corp.

145 Adams Ave., Hauppauge, NY 11788 USA
Phone (631) 435-1110 FAX (631) 435-1824

Manufacturers of World Class Discrete Semiconductors
www.centrasemi.com

BRX44 SERIES

SILICON CONTROLLED RECTIFIER

TO-92 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR BRX44 series types are PNP Silicon Controlled Rectifiers manufactured in a TO-92 case, designed for control systems and sensing circuit applications.

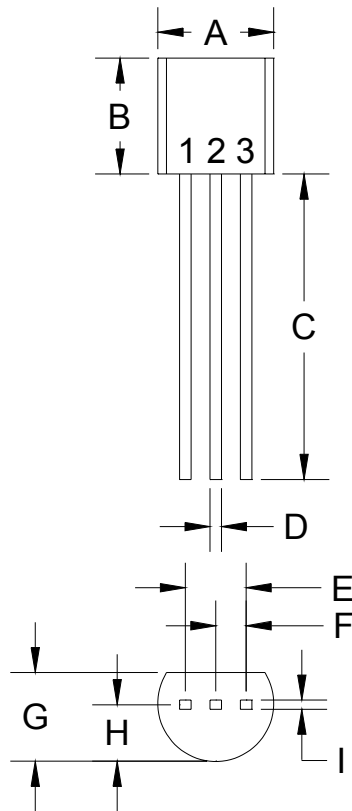
MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

	<u>SYMBOL</u>	<u>BRX44</u>	<u>BRX45</u>	<u>BRX46</u>	<u>BRX47</u>	<u>BRX48</u>	<u>BRX49</u>	<u>UNITS</u>
Peak Repetitive Off-State Voltage	V_{DRM}, V_{RRM}	30	60	100	200	300	400	V
RMS On-State Current ($T_C=40^\circ\text{C}$)	$I_T(\text{RMS})$				0.8			A
Average On-State Current ($T_C=40^\circ\text{C}$)	$I_T(\text{AV})$				0.5			A
Nonrept. On-State Current ($T_C=60^\circ\text{C}$)	I_{TSM}				10			A
Fusing Current ($t=10\text{ms}$)	I^2t				0.24			A^2s
Peak Reverse Gate Voltage ($I_{GR}=10\mu\text{A}$)	V_{GRM}				8.0			V
Peak Gate Current ($t=10\mu\text{s}$)	I_{GM}				1.0			A
Peak Gate Dissipation ($t=10\mu\text{s}$)	P_{GM}				2.0			W
Gate Dissipation ($t=20\text{ms}$)	$P_G(\text{AV})$				0.1			W
Operating and Storage Junction Temperature	T_J, T_{stg}				-40 to +125			$^\circ\text{C}$
Thermal Resistance	θ_{JC}				100			$^\circ\text{C}/\text{W}$
Thermal Resistance	θ_{JA}				200			$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MIN</u>	<u>MAX</u>	<u>UNITS</u>
I_{DRM}, I_{RRM}	Rated $V_{DRM}, V_{RRM}, R_{GK}=1.0\text{k}\Omega, T_C=125^\circ\text{C}$		0.1	mA
I_{DRM}, I_{RRM}	Rated $V_{DRM}, V_{RRM}, R_{GK}=1.0\text{k}\Omega, T_C=25^\circ\text{C}$		1.0	μA
V_{TM}	$I_T=1.0\text{A}$		1.7	V
I_{GT}	$V_D=6.0\text{V}, R_L=10\Omega$		200	μA
V_{GT}	$V_D=6.0\text{V}, R_L=10\Omega$		0.8	V
I_H	$R_{GK}=1\text{k}\Omega$		5.0	mA
I_L	$R_{GK}=1\text{k}\Omega$		6.0	mA
dv/dt	$V_D=0.67\text{V} \times V_{DRM}, R_{GK}=1.0\text{k}\Omega, T_C=125^\circ\text{C}$	100		$\text{V}/\mu\text{s}$
di/dt	$I_G=10\text{mA}, di_G/dt=0.1\text{A}/\mu\text{s}, T_C=125^\circ\text{C}$	30		$\text{A}/\mu\text{s}$

(SEE REVERSE SIDE)

TO-92 PACKAGE - MECHANICAL OUTLINE

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

Lead Code: 1) Anode
 2) Gate
 3) Cathode

R1

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